

## **Vishay Semiconductors**

# **Small Signal Schottky Diodes**

#### **Features**

- These diodes feature very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
  - (e3)
- These diodes are also available in the DO35 case with the type designations BAT42 to BAT43, in MiniMELF SOD80 case with the type designations LL42 to LL43, and in SOD123 plastic case with the type designations BAT42W-V to BAT43W-V
- For general purpose applications
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Case: SOD323 plastic case Weight: approx. 4.3 mg Packaging codes/options:

GS18/10 k per 13" reel (8 mm tape), 10 k/box GS08/3 k per 7" reel (8 mm tape), 15 k/box



Part	Ordering code	Type marking	Remarks
BAT42WS-V	BAT42WS-V-GS18 or BAT42WS-V-GS08	L2	Tape and reel
BAT43WS-V	BAT43WS-V-GS18 or BAT43WS-V-GS08	L3	Tape and reel

### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		$V_{RRM}$	30	V
Forward continuous current	T <sub>amb</sub> = 25 °C	I <sub>F</sub>	200 <sup>1)</sup>	mA
Repetitive peak forward current	$t_p < 1 \text{ s, } \delta < 0.5, T_{amb} = 25 \text{ °C}$	I <sub>FRM</sub>	500 <sup>1)</sup>	mA
Surge forward current	$t_p$ < 10 ms, $T_{amb}$ = 25 °C	I <sub>FSM</sub>	4 <sup>1)</sup>	Α
Power dissipation 1)	T <sub>amb</sub> = 25 °C	P <sub>tot</sub>	150 <sup>1)</sup>	mW

#### Note:

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<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature

# BAT42WS-V/BAT43WS-V

## **Vishay Semiconductors**



#### **Thermal Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

and				
Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		$R_{thJA}$	650 <sup>1)</sup>	K/W
Junction temperature		T <sub>j</sub>	125	°C
Ambient operating temperature range		T <sub>amb</sub>	- 55 to + 125	°C
Storage temperature range		T <sub>stg</sub>	- 55 to + 150	°C

Note:

#### **Electrical Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min.	Тур.	Max.	Unit
Reverse breakdown voltage	$I_R = 100 \mu A \text{ (pulsed)}$		$V_{(BR)}$	30			V
Leakage current 1)	V <sub>R</sub> = 25 V		I <sub>R</sub>			0.5	μΑ
	V <sub>R</sub> = 25 V, T <sub>j</sub> = 100 °C		I <sub>R</sub>			100	μΑ
Forward voltage <sup>1)</sup>	I <sub>F</sub> = 200 mA		V <sub>F</sub>			1000	mV
	I <sub>F</sub> = 10 mA	BAT42WS-V	V <sub>F</sub>			400	mV
	I <sub>F</sub> = 50 mA	BAT42WS-V	V <sub>F</sub>			650	mV
	I <sub>F</sub> = 2 mA	BAT43WS-V	$V_{F}$	260		330	mV
	I <sub>F</sub> = 15 mA	BAT43WS-V	$V_{F}$			450	mV
Diode capacitance	V <sub>R</sub> = 1 V, f = 1 MHz		C <sub>D</sub>		7		pF
Reverse recovery time	$I_F = 10 \text{ mA}, I_R = 10 \text{ mA},$ $I_R = 1 \text{ mA}, R_L = 100 \Omega$		t <sub>rr</sub>			5	ns
Rectification efficieny	$R_L = 15 \text{ k}\Omega, C_L = 300 \text{ pF},$ $f = 45 \text{ MHz}, V_{RF} = 2 \text{ V}$		$\eta_{V}$	80			%

Note:

## **Typical Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

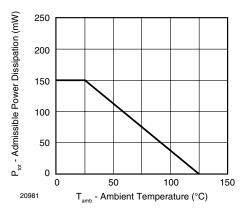


Figure 1. Admissible Power Dissipation vs. Ambient Temperature

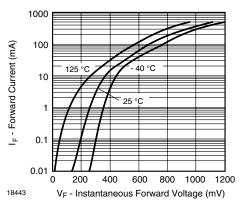


Figure 2. Typical Reverse Characteristics

<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature

<sup>&</sup>lt;sup>1)</sup> Pulse test  $t_p < 300 \ \mu s, \ t_p/T < 0.02$ 

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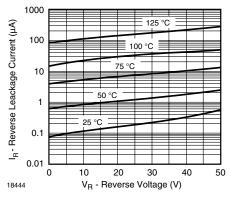


Figure 3. Typical Reverse Characteristics

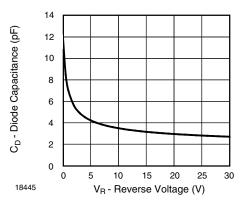
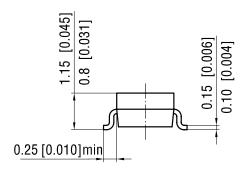
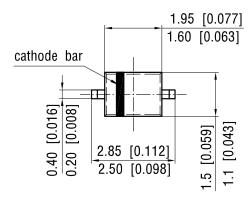


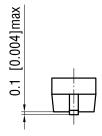
Figure 4. Typical Capacitance vs. Reverse Voltage

## Package Dimensions in millimeters (inches): SOD323

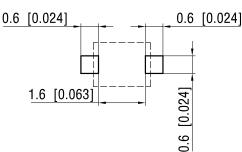




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# BAT42WS-V/BAT43WS-V

### **Vishay Semiconductors**



#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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For technical support, please contact: <u>Diodes-SSP@vishay.com</u>

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# **Legal Disclaimer Notice**



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